S22MD2

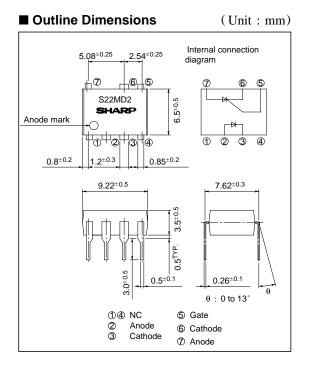
Photothyristor Coupler

Features

- Long distance between anode and cathode of photothyristor on the output side : 5.08mm
- 2. High repetitive peak OFF-state voltage (V_{DRM} : MIN. 600V)
- 3. Low trigger current (I_{FT} : MAX. 8mA at $R_{\rm G}$ = 20k Ω)
- 4. High isolation voltage between input and output (V_{iso} : 5 000V_{rms})
- * S22MD2 is for 200V line.

Applications

- 1. ON-OFF operation for a low power load
- 2. For triggering high power thyristor and triac



Absolute Maximum Ratings

$(Ta = 25^{\circ}C)$

	Parameter	Symbol	Rating	Unit
Input	Forward current	I_F	50	mA
	Reverse voltage	VR	6	V
Output	RMS ON-state current	IT	200	mArms
	*1Peak one cycle surge current	I surge	2	A
	*2Repetitive peak OFF-state voltage	VDRM	600	V
	*2Repetitive peak reverse voltage	V _{RRM}	600	V
*3Isolation voltage		V _{iso}	5 000	V _{rms}
Operating temperature		T opr	- 30 to +100	°C
Storage temperature		T stg	- 40 to +125	°C
*4Soldering temperature		T _{sol}	260	°C

*1 50Hz, sine wave

 $*2 R_G = 20k\Omega$

*3 40 to 60% RH, AC for 1 minute

*4 For 10 seconds

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Electro-optical Characteristics $(Ta = 25^{\circ}C)$ Parameter Symbol Conditions MIN. TYP. MAX. Unit $I_F = 30 m A$ Forward voltage VF _ 1.2 1.4 v Input Reverse current I_R $V_R = 4V$ 10-5 Α _ _ Repetitive peak OFF-state current I drm $V_{DRM} = Rated, R_G = 20k\Omega$ _ 10-6 А _ Repetitive peak reverse current $V_{RRM} = Rated, R_G = 20k\Omega$ 10-6 I_{RRM} _ Α _ ON-state voltage Vт $I_T = 200 \text{mA}$ 1.4 V Output 1.0 _ Holding current $I_{\rm H}$ $V_D = 6V, R_G = 20k\Omega$ 0.3 1 mA _ Critical rate of rise of OFF-state voltage dV/dt $V_{DRM} = 1/\sqrt{2}$ Rated, $R_G = 20k\Omega$ 3 V/µs _ Minimum trigger current $I_{\,\rm FT}$ $V_D = 6V, R_L = 100\Omega, R_G = 20k\Omega$ 6 8 mA _ Transfer-1011 Isolation resistance DC500V, 40 to 60% RH $5x \ 10^{10}$ R ISO Ω _ charac- $V_D = 6V, R_G = 20k\Omega, R_L = 100\Omega, I_F =$ teristics Turn-on time 20 50 t_{on} μs 30mA

Fig. 1 RMS ON-state Current vs. Ambient Temperature

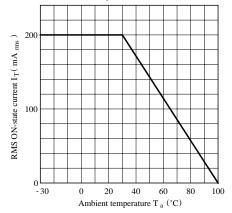


Fig. 3 Forward Current vs. Forward Voltage

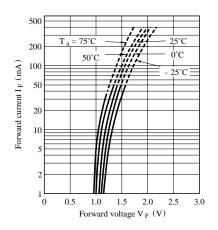


Fig. 2 Forward Current vs. Ambient Temperature

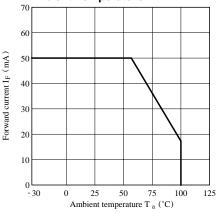
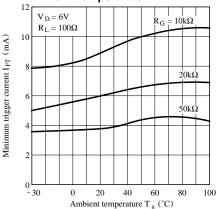


Fig. 4 Minimum Trigger Current vs. Ambient Temperature



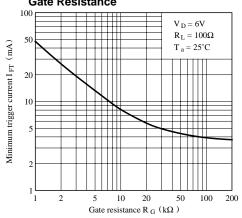
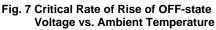
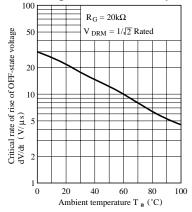
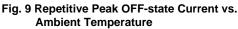
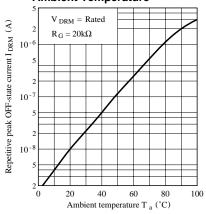


Fig. 5 Minimum Trigger Current vs. Gate Resistance











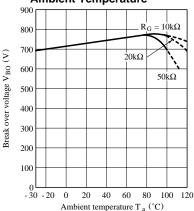
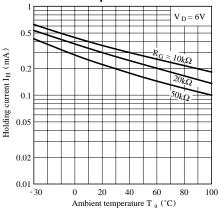
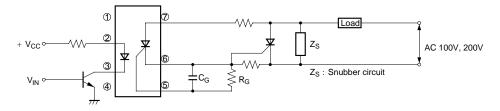


Fig. 8 Holding Current vs. Ambient Temperature

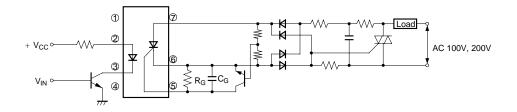


Basic Operation Circuit





Medium/High Power Triac Drive Circuit (Zero-cross Operation)



• Please refer to the chapter "Precautions for Use" (Page 78 to 93).

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- Various safety devices, etc.

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